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## 3.3 V / 2.5 V Programmable OmniClock Generator

## **with Single Ended (LVCMOS/LVTTL) and Differential (LVPECL/LVDS/ HCSL/CML) Outputs**

The NB3H60113G, which is a member of the OmniClock family, is a one−time programmable (OTP), low power PLL−based clock generator that supports any output frequency from 8 kHz to 200 MHz. The device accepts fundamental mode parallel resonant crystal or a single ended (LVCMOS/LVTTL) reference clock as input. It generates either three single ended (LVCMOS/LVTTL) outputs, or one single ended output and one differential (LVPECL/LVDS/HCSL/CML) output. The output signals can be modulated using the spread spectrum feature of the PLL (programmable spread spectrum type, deviation and rate) for applications demanding low electromagnetic interference (EMI). Using the PLL bypass mode, it is possible to get a copy of the input clock on any or all of the outputs. The device can be powered down using the Power Down pin (PD#). It is possible to program the internal input crystal load capacitance and the output drive current provided by the device. The device also has automatic gain control (crystal power limiting) circuitry which avoids the device overdriving the external crystal.

#### **Features**

- Member of the OmniClock Family of Programmable Clock **Generators**
- Operating Power Supply: 3.3 V  $\pm$  10%, 2.5 V  $\pm$  10%
- I/O Standards
	- ♦ Inputs: LVCMOS/LVTTL, Fundamental Mode Crystal
	- ♦ Outputs: LVCMOS/LVTTL
	- ♦ Outputs: LVPECL, LVDS, CML and HCSL
- 3 Programmable Single Ended (LVCMOS/LVTTL) Outputs from 8 kHz to 200 MHz
- 1 Programmable Differential Clock Output up to 200 MHz
- Input Frequency Range
	- ♦ Crystal: 3 MHz to 50 MHz
	- ♦ Reference Clock: 3 MHz to 200 MHz
- Configurable Spread Spectrum Frequency Modulation Parameters (Type, Deviation, Rate)
- Programmable Internal Crystal Load Capacitors
- Programmable Output Drive Current for Single Ended **Outputs**





**CASE 511AT**

#### **MARKING DIAGRAM**



(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 21 of this data sheet.

- Power Saving mode through Power Down Pin
- Programmable PLL Bypass Mode
- Programmable Output Inversion
- Programming and Evaluation Kit for Field Programming and Quick Evaluation
- Temperature Range −40°C to 85°C
- Packaged in 8−Pin WDFN
- These are Pb−Free Devices

#### **Typical Applications**

- eBooks and Media Players
- Smart Wearables, Portable Medical and Industrial Equipment
- Set Top Boxes, Printers, Digital Cameras and **Camcorders**

#### **BLOCK DIAGRAM**



#### **Notes:**

1. CLK0 and CLK1 can be configured to be one of LVPECL, LVDS, HCSL or CML output, or two single−ended LVCMOS/ LVTTL outputs.

2. Dotted lines are the programmable control signals to internal IC blocks.

3. PD# has internal pull down resistor.

#### **Figure 1. Simplified Block Diagram**



### **PIN FUNCTION DESCRIPTION**



#### **Table 1. PIN DESCRIPTION**



#### **Table 2. POWER DOWN FUNCTION TABLE**



#### **TYPICAL CRYSTAL PARAMETERS**

Crystal: Fundamental Mode Parallel Resonant Frequency: 3 MHz to 50 MHz

#### **Table 3. MAX CRYSTAL LOAD CAPACITORS RECOMMENDATION**



Shunt Capacitance (C0): 7 pF (Max) Equivalent Series Resistance (ESR):  $150 \Omega$  (Max)

#### **FUNCTIONAL DESCRIPTION**

The NB3H60113G is a 3.3 V / 2.5 V programmable, single ended / differential clock generator, designed to meet the clock requirements for consumer and portable markets. It has a small package size and it requires low power during operation and while in standby. This device provides the

ability to configure a number of parameters as detailed in the following section. The One−Time Programmable memory allows programming and storing of one configuration in the memory space.



**Figure 3. Power Supply Noise Suppression**

#### **Power Supply**

#### **Device Supply**

The NB3H60113G is designed to work with a 3.3 V/2.5 V VDD power supply. For VDD operation of 1.8 V, refer to NB3V60113G datasheet. In order to suppress power supply noise it is recommended to connect decoupling capacitors of  $0.1 \mu$ F and  $0.01 \mu$ F close to the VDD pin as shown in Figure 3.

#### **Clock Input**

#### **Input Frequency**

The clock input block can be programmed to use a fundamental mode crystal from 3 MHz to 50 MHz or a single ended reference clock source from 3 MHz to 200 MHz. When using output frequency modulation for EMI reduction, for optimal performance, it is recommended to use crystals with frequency more than 6.75 MHz as input. Crystals with ESR values of up to 150  $\Omega$  are supported. When using a crystal input, it is important to set crystal load capacitor values correctly to achieve good performance.

#### **Programmable Crystal Load Capacitors**

The provision of internal programmable crystal load capacitors eliminates the necessity of external load capacitors for standard crystals. The internal load capacitor can be programmed to any value between 4.36 pF and 20.39 pF with a step size of 0.05 pF. Refer to Table 3 for recommended maximum load capacitor values for stable operation. There are three modes of loading the crystal – with internal chip capacitors only, with external capacitors only or with the both internal and external capacitors. Check with the crystal vendor's load capacitance specification for setting of the internal load capacitors. The minimum value of 4.36 pF internal load capacitor need to be considered while selecting external capacitor value. These will be bypassed when using an external reference clock.

#### **Automatic Gain Control (AGC)**

The Automatic Gain Control (AGC) feature adjusts the gain to the input clock based on its signal strength to maintain a good quality input clock signal level. This feature takes care of low clock swings fed from external reference clocks and ensures proper device operation. It also enables maximum compatibility with crystals from different manufacturers, processes, quality and performance. AGC also takes care of the power dissipation in the crystal; avoids over driving the crystal and thus extending the crystal life. In order to calculate the AGC gain accurately and avoid increasing the jitter on the output clocks, the user needs to provide crystal load capacitance as well as other crystal parameters like ESR and shunt capacitance (C0).

## **Programmable Clock Outputs**

### **Output Type and Frequency**

The NB3H60113G provides three independent single ended LVCMOS/LVTTL outputs, or one single ended LVCMOS/LVTTL output and one LVPECL/LVDS/HCSL/ CML differential output. The device supports any single ended output or differential output frequency from 8 kHz up to 200 MHz with or without frequency modulation. It should be noted that certain combinations of output frequencies and spread spectrum configurations may not be recommended for optimal and stable operation.

For differential clocking, CLK0 and CLK1 can be configured as LVPECL, LVDS, HCSL or CML. Refer to the Application Schematic in Figure 4.



**Figure 4. Application Setup for Differential Output Configuration**

#### **Programmable Output Drive**

The drive strength or output current of each of the LVCMOS clock outputs is programmable. For  $V_{DD}$  of 3.3 V and 2.5 V four distinct levels of LVCMOS output drive strengths can be selected as mentioned in the DC Electrical Characteristics. This feature provides further load drive and signal conditioning as per the application requirement.

#### **PLL BYPASS Mode**

PLL Bypass mode can be used to buffer the input clock on any of the outputs or all of the outputs. Any of the clock outputs can be programmed to generate a copy of the input clock.

#### **Output Inversion**

All output clocks of the NB3H60113G can be phase inverted relative to each other. This feature can also be used in conjunction with the PLL Bypass mode.

#### **Spread Spectrum Frequency Modulation**

Spread spectrum is a technique using frequency modulation to achieve lower peak electromagnetic interference (EMI). It is an elegant solution compared to techniques of filtering and shielding. The NB3H60113G modulates the output of its PLL in order to "spread" the bandwidth of the synthesized clock, decreasing the peak amplitude at the center frequency and at the frequency's harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most clock generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum modulation'.



**Figure 5. Frequency Modulation or Spread Spectrum Clock for EMI Reduction**

The outputs of the NB3H60113G can be programmed to have either center spread from  $\pm 0.125\%$  to  $\pm 3\%$  or down spread from  $-0.25\%$  to  $-4\%$ . The programmable step size for spread spectrum deviation is 0.125% for center spread and 0.25% for down spread respectively. Additionally, the frequency modulation rate is also programmable. Frequency modulation from 30 kHz to 130 kHz can be selected. Spread spectrum, when on, applies to all the outputs of the device but not to output clocks that use the PLL bypass feature. There exists a tradeoff between the input clock frequency and the desired spread spectrum profile. For certain combinations of input frequency and modulation rate, the device operation could be unstable and should be avoided. For spread spectrum applications, the following limits are recommended:

 $Fin$  (Min) = 6.75 MHz Fmod (range) =  $30$  kHz to 130 kHz Fmod  $(Max) = Fin / 225$ 

For any input frequency selected, above limits must be observed for a good spread spectrum profile.

For example, the minimum recommended reference frequency for a modulation rate of 30 kHz would be 30 kHz  $*$  225 = 6.75 MHz. For 27 MHz, the maximum recommended modulation rate would be  $27$  MHz  $/$   $225 = 120$  kHz.

#### **Control Inputs**

#### **Power Down**

Power saving mode can be activated through the power down PD# input pin. This input is an LVCMOS/LVTTL active Low Master Reset that disables the device and sets outputs Low. By default it has an internal pull−down resistor. The chip functions are disabled by default and when PD# pin is pulled high the chip functions are activated.

#### **Configuration Space**

NB3H60113G has one Configuration. Table 4 shows an example of device configuration.

#### **Table 4. EXAMPLE CONFIGURATION**



#### **Default Device State**

The NB3H60113G parts shipped from ON Semiconductor are blank, with no inputs/outputs programmed. These need to be programmed by the field sales or distribution or by the user themselves before they can be used. Programmable clock software downloadable from the ON Semiconductor website can be used along with the programming kit to achieve this purpose. For mass production, parts can be programmed with a customer qualified configuration and sourced from ON Semiconductor as a dash part number (Eg. NB3H60113G−01).

#### **Table 5. ATTRIBUTES**



1. For additional information, see Application Note AND8003/D.

#### **Table 6. ABSOLUTE MAXIMUM RATING** (Note 2)



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and not valid simultaneously. If stress limits are exceeded device functional operation is not implied, damage may occur and reliability may be affected.

3. JEDEC standard multilayer board − 2S2P (2 signal, 2 power). ESD51.7 type board. Back side Copper heat spreader area 100 sq mm, 2 oz (0.070 mm) copper thickness.

#### **Table 7. RECOMMENDED OPERATION CONDITIONS**



Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. The XIN / XOUT pin stray capacitance needs to be subtracted from crystal load capacitance (along with PCB and trace capacitance) while selecting appropriate load for the crystal in order to get minimum ppm error.





**Table 8. DC ELECTRICAL CHARACTERISTICS** (V<sub>DD</sub> = 3.3 V ± 10%, 2.5 V ± 10%; GND = 0 V, T<sub>A</sub> = −40°C to 85°C, Notes 5, 17)



#### **LVDS OUTPUTS** (Notes 8 and 11)



#### **LVPECL OUTPUTS** (Notes 14 and 15)



#### **CML OUTPUTS** (Notes 15 and 16)



NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 5. Measurement taken with single ended clock outputs terminated with test load capacitance of 5 pF and 15 pF and differential clock terminated with test load of 2 pF. See Figures 7, 8 and 13. Specification for LVTTL are valid for the V<sub>DD</sub> 3.3 V only.
- 6. Measurement taken with outputs terminated with RS = 0  $\Omega$ , RL = 50  $\Omega$ , with test load capacitance of 2 pF. See Figure 8. Guaranteed by characterization.
- 7. Measurement taken from single−ended waveform.
- 8. Measured at crossing point where the instantaneous voltage value of the rising edge of CLKx+ equals the falling edge of CLKx−.
- 9. Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.
- 10.Defined as the total variation of all crossing voltage of rising CLKx+ and falling CLKx−. This is maximum allowed variance in the VCROSS for any particular system.
- 11. LVDS outputs require 100  $\Omega$  receiver termination resistor between differential pair. See Figure 9.
- 12.VOHmax = VOSmax + 1/2 VODmax.
- 13. VOLmax = VOSmin 1/2 VODmax.
- 14. LVPECL outputs loaded with 50  $\Omega$  to V<sub>DD</sub> 2.0 V for proper operation.
- 15. Output parameters vary 1:1 with  $V_{DD}$ .
- 16. CML outputs loaded with 50  $\Omega$  to V<sub>DD</sub> for proper operation.
- 17.Parameter guaranteed by design verification not tested in production.

#### **Table 9. AC ELECTRICAL CHARACTERISTICS**

(V<sub>DD</sub> = 3.3 V ± 10%; 2.5 V ± 10%, GND = 0 V, T<sub>A</sub> = −40°C to 85°C, Notes 18, 19 and 22)



**SINGLE ENDED OUTPUTS** (V<sub>DD</sub> = 3.3 V ±10%, 2.5 V ±10%;  $T_A$  = -40°C to 85°C, Notes 18, 19 and 22)



#### **DIFFERENTIAL OUTPUT (CLK1, CLK0)** (V<sub>DD</sub> = 3.3 V, ±10% 2.5 V ±10%; T<sub>A</sub> = −40°C to 85°C, Notes 18, 22 and 23)



#### **Table 9. AC ELECTRICAL CHARACTERISTICS**

 $(V_{DD} = 3.3 V \pm 10\%$ ; 2.5 V  $\pm$  10%, GND = 0 V, T<sub>A</sub> = -40°C to 85°C, Notes 18, 19 and 22)



NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

18.Parameter guaranteed by design verification not tested in production.

19.Measurement taken from single ended clock terminated with test load capacitance of 5 pF and 15 pF and differential clock terminated with test load of 2 pF. See Figures 6, 7 and 12.

20.Measurement taken from single−ended waveform

21.Measurement taken from differential waveform

22.AC performance parameters like jitter change based on the output frequency, spread selection, power supply and loading conditions of the output. For application specific AC performance parameters, please contact ON Semiconductor.

23. Measured at  $f_{\text{out}}$  = 100 MHz, No Frequency Modulation, fclkin = 25 MHz fundamental mode crystal and output termination as described in Parameter Measurement Test Circuits

24.Period jitter Sampled with 10000 cycles, Cycle−cycle jitter sampled with 1000 cycles. Jitter measurement may vary. Actual jitter is dependent on Input jitter and edge rate, number of active outputs, inputs and output frequencies, supply voltage, temperature, and output load.





25.Receiver VCC must be at same supply potential as VDD for differential clock outputs.26.All resistor values are in ohms.

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#### **PARAMETER MEASUREMENT TEST CIRCUITS**



**Figure 7. LVCMOS/LVTTL Parameter Measurement**



**Figure 8. HCSL Parameter Measurement**







**Figure 10. LVPECL Parameter Measurement**



### **TIMING MEASUREMENT DEFINITIONS**



**Figure 12. LVCMOS Measurement for AC Parameters**



**Figure 13. Differential Measurement for AC Parameters**





**Figure 15. Output Enable/ Disable and Power Down Functions**

#### **APPLICATION GUIDELINES**

#### **Crystal Input Interface**

Figure 16 shows the NB3H60113G device crystal oscillator interface using a typical parallel resonant fundamental mode crystal. A parallel crystal with loading capacitance  $C_L = 18$  pF would use  $C1 = 32$  pF and  $C2 =$ 32 pF as nominal values, assuming 4 pF of stray capacitance per line.

$$
C_L = (C1 + Cstray)/2
$$
; C1 = C2

The frequency accuracy and duty cycle skew can be fine−tuned by adjusting the C1 and C2 values. For example, increasing the C1 and C2 values will reduce the operational frequency. Note R1 is optional and may be  $0 \Omega$ .



**Figure 16. Crystal Interface Loading**

#### **Output Interface and Terminations**

The NB3H60113G consists of a unique Multi Standard Output Driver to support LVCMOS/LVTTL, LVDS, LVPECL, CML and HCSL standards. Termination techniques required for each of these standards are different to ensure proper functionality. The required termination changes must be considered and taken care of by the system designer.

#### **LVCMOS/ LVTTL Interface**

LVCMOS/ LVTTL output swings rail-to-rail up to V<sub>DD</sub> supply and can drive up to 15 pF load at higher drive strengths. The output buffer's drive is programmable up to four steps, though the drive current will depend on the step setting as well as the  $V_{DD}$  supply voltage. (See Figure 17 and Table 10). Drive strength must be configured high for driving higher loads. The slew rate of the clock signal increases with higher output current drive for the same load. The software lets the user choose the load drive current value per LVCMOS/LVTTL output based on the V<sub>DD</sub> supply selected.

the cap load posed by the receiver input pin.  $C_{load} = (CL +$ 

An optional series resistor Rs can be connected at the output for impedance matching, to limit the overshoots and



Cpin+ Cin)

ringings.

#### **Table 10. LVCMOS/ LVTTL DRIVE LEVEL SETTINGS**

The load current consists of the static current component (varies with drive) and dynamic current component. For any supply voltage, the dynamic load current range per LVCMOS output can be approximated by formula –

## $IDD = f_{out} * C_{load} * VDD$

Cload includes the load capacitor connected to the output, the pin capacitor posed by the output pin (typically 5 pF) and



**Figure 17. Simplified LVCMOS Output Structure**

#### **LVDS Interface**

Differential signaling like LVDS has inherent advantage of common mode noise rejection and low noise emission, and thus a popular choice clock distribution in systems. TIA/EIA−644 or LVDS is a standard differential, point−to−point bus topology that supports fast switching speeds and has benefit of low power consumption. The

driver consists of a low swing differential with constant current of 3.5 mA through the differential pair, and generates switching output voltage across a 100  $\Omega$ terminating resistor (externally connected or internal to the receiver). Power dissipation in LVDS standard  $((3.5 \text{ mA})^2 \text{ x})$  $100 \Omega = 1.2 \text{ mW}$  is thus much lower than other differential signalling standards.

A fan−out LVDS buffer (like ON Semiconductor's NB6N1xS and NB6L1xS) can be used as an extension to provide clock signal to multiple LVDS receivers to drive multiple point−to−point links to receiving node.



**Figure 18. Simplified LVDS Output Structure with Termination**

#### **LVPECL Interface**

The LVPECL driver is designed to drive a 50  $\Omega$ transmission line from a constant current differential and a low impedance emitter follower. On the NB3H60113G, this differential standard is supported for  $V_{DD}$  supply voltage of 2.5 V and above. In the system, the clock receiver must be referenced at the same supply voltage as  $V_{DD}$  for reliable functionality. The termination to  $V_{CC}$  – 2 V (1.3 V for a 3.3 V  $V_{DD}$  supply, and 0.5 V for a 2.5 V  $V_{DD}$  supply) used in evaluation boards, is rarely used in system boards as it adds another power supply on the system board. Thus, Thevenin's equivalent circuit (Figure 20) for this termination or a Y−type termination (Figure 21) is often used in systems. Termination techniques for LVPECL are detailed in the application note "Termination of ECL Devices with EF (Emitter Follower) OUTPUT Structure − AND8020".



**Figure 19. Simplified LVPECL Output Structure with Termination**



**Figure 20. LVPECL Thevenin Termination**





**Figure 21. LVPECL Y−Termaination**



The termination should be placed as close to the receiver as possible to avoid unterminated stubs that can cause signal integrity issues.

#### **CML Interface**

A CML driver consists of an NMOS open drain constant current differential driving 16 mA current into a 50  $\Omega$  load terminated to the supply voltage at the receiver. This termination resistor can be external or internal to the receiver and needs to be as close as possible to the receiver. The termination techniques used for a CML driver are detailed in application note "Termination and Interface of ON Semiconductor ECL Devices With CML (Current Mode Logic) OUTPUT Structure – AND8173".



**Figure 22. Simplified CML Output Structure with Termination**

#### **HCSL Termination**

HCSL is a differential signaling standard commonly used in PCIe systems. The HCSL driver is typical 14.5 mA switched current open source output that needs a 50  $\Omega$ termination resistor to ground near the source, and generates 725 mV of signal swing. A series resistor (10  $\Omega$  to 33  $\Omega$ ) is

optionally used to achieve impedance matching by limiting overshoot and ringing due to the rapid rise of current from the output driver. The open source driver has high internal impedance, thus a series resistor up to 33  $\Omega$  does not affect the signal integrity. This resistor can be avoided for low V<sub>DD</sub> supply of operation, unless impedance matching requires it.



**Figure 23. Simplified HCSL Output Structure with Termination**

#### **Field Programming Kit and Software**

The NB3H60113G can be programmed by the user using the 'Clock Cruiser Programmable Clock Kit'. This device uses the 8L daughter card on the hardware kit. To design a new clock, 'Clock Cruiser Software' is required to be installed from the ON Semiconductor website. The user manuals for the hardware kit Clock Cruiser Programmable Clock Kit and Clock Cruiser Software can be found following the link **www.onsemi.com**.

#### **Recommendation for Clock Performance**

Clock performance is specified in terms of Jitter in time the domain and Phase noise in frequency domain. Details

and measurement techniques of Cycle−cycle jitter, period jitter, TIE jitter and Phase Noise are explained in application note AND8459/D.

In order to have a good clock signal integrity for minimum data errors, it is necessary to reduce the signal reflections. Reflection coefficient can be zero only when the source impedance equals the load impedance. Reflections are based on signal transition time (slew rate) and due to impedance mismatch. Impedance matching with proper termination is required to reduce the signal reflections. The amplitude of overshoots is due to the difference in impedance and can be minimized by adding a series resistor (Rs) near the output

pin. Greater the difference in impedance, greater is the amplitude of the overshoots and subsequent ripples. The ripple frequency is dependant on the signal travel time from the receiver to the source. Shorter traces results in higher ripple frequency, as the trace gets longer the travel time increases, reducing the ripple frequency. The ripple frequency is independent of signal frequency, and only depends on the trace length and the propagation delay. For eg. On an FR4 PCB with approximately 150 ps/ inch of propagation rate, on a 2 inch trace, the ripple frequency  $= 1$  $/(150 \text{ ps} * 2 \text{ inch} * 5) = 666.6 \text{ MHz};$  [5 = number of times] the signal travels, 1 trip to receiver plus 2 additional round trips]

PCB traces should be terminated when trace length tr/f /  $(2^*$  tprate); tr/f = rise/ fall time of signal, tprate = propagation rate of trace.



**Figure 24. Signal Reflection Components**

#### **PCB Design Recommendation**

For a clean clock signal waveform it is necessary to have a clean power supply for the device. The device must be isolated from system power supply noise. A  $0.1 \mu$ F and a  $2.2 \mu$ F decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitor and VDD pin. The PCB trace to VDD pin and the ground via should be kept thicker and as short as possible. All the VDD pins should have decoupling capacitors.

Stacked power and ground planes on the PCB should be large. Signal traces should be on the top layer with minimum vias and discontinuities and should not cross the reference planes. The termination components must be placed near the source or the receiver. In an optimum layout all components are on the same side of the board, minimizing vias through other signal layers.

#### **Device Applications**

The NB3H60113G is targeted mainly for the Consumer market segment and can be used as per the examples below.

#### **Clock Generator**

Consumer applications like a Set top Box, have multiple sub−systems and standard interfaces and require multiple reference clock sources at various locations in the system. This part can function as a clock generating IC for such applications generating a reference clock for interfaces like USB, Ethernet, Audio/Video, ADSL, PCI etc.



**Figure 25. Application as Clock Generator**

#### **Buffer and Logic/Level Translator**

The NB3H60113G is useful as a simple CMOS Buffer in PLL bypass mode. One or more outputs can use the PLL Bypass mode to generate the buffered outputs. If the PLL is configured to use spread spectrum, all outputs using PLL Bypass feature will not be subjected to the spread spectrum. The device can be simultaneously used as logic translator for converting the LVCMOS input clock to HCSL, LVDS, LVPECL, or CML.

For instance this device can be used in applications like an LCD monitor, for converting the LVCMOS input clock to LVDS output.



NOTE: LVCMOS signal level cannot be translated to a higher level of LVCMOS voltage.

#### **EMI Attenuator**

Spread spectrum through frequency modulation technique enables the reduction of the EMI radiated from the high frequency clock signals by spreading the spectral energy to the nearby frequencies. While using frequency modulation, the same selection is applied to all the PLL

clock outputs (not bypass outputs) even if they are at different frequencies. In Figure 27, CLK0 uses the PLL and hence is subjected to the spread spectrum modulation while CLK1 and CLK2 use the PLL Bypass mode and hence are not subjected to the spread spectrum modulation.



**Figure 27. Application as EMI Attenuator**

#### **ORDERING INFORMATION**



†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **PACKAGE DIMENSIONS**



details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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